## NSN 5961-00-927-5356

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View Online at https://aerobasegroup.com/nsn/5961-00-927-5356 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Overall Diameter:** 0.230 inches **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal **Semiconductor Material:** Silicon all semiconductor **Voltage Rating In Volts Per Characteristic:** 50.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes source cutoff current absolute all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all semiconductor **Test Data Document:** 94853-301870 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: